

**Amendments to the Claims:**

The following listing of claims will replace all prior versions, and listings, of claims in the application:

1. (Currently Amended) An information-recording medium comprising a substrate and a recording layer which is rewritable in accordance with phase-change caused by being irradiated with a laser beam, the information recording medium further comprising at least one other layer formed over the recording layer, wherein the recording layer ~~contains~~ consists of Bi, Ge, and Te, and composition ratios thereof are within a range surrounded by the following respective points on a triangular composition diagram having apexes corresponding to Bi, Ge, and Te, and the recording layer has a film thickness of not more than 15 nm:

F3 (Bi<sub>3.5</sub>, Ge<sub>46</sub>, Te<sub>50.5</sub>);

C3 (Bi<sub>4</sub>, Ge<sub>46</sub>, Te<sub>50</sub>);

D3 (Bi<sub>5</sub>, Ge<sub>46</sub>, Te<sub>49</sub>);

D5 (Bi<sub>10</sub>, Ge<sub>42</sub>, Te<sub>48</sub>);

C5 (Bi<sub>10</sub>, Ge<sub>41</sub>, Te<sub>49</sub>);

F5 (Bi<sub>7.5</sub>, Ge<sub>41</sub>, Te<sub>51.5</sub>).

2. (Currently Amended) An information-recording medium comprising a substrate and a recording layer which is rewritable in accordance with phase-change caused by being irradiated with a laser beam, the information recording medium further comprising at least one other layer formed over the recording layer, wherein the recording layer ~~contains~~ consists of Bi, Ge, and Te, and composition ratios thereof are within a range surrounded by the following respective points on a triangular composition diagram having apexes corresponding to Bi, Ge, and Te, and the recording layer has a film thickness of not more than 15 nm:

F2 (Bi<sub>2.5</sub>, Ge<sub>47</sub>, Te<sub>50.5</sub>);

C2 (Bi<sub>3</sub>, Ge<sub>47</sub>, Te<sub>50</sub>);

D2 (Bi<sub>4</sub>, Ge<sub>47</sub>, Te<sub>49</sub>);

D6 (Bi<sub>16</sub>, Ge<sub>37</sub>, Te<sub>47</sub>);

C8 (Bi<sub>30</sub>, Ge<sub>22</sub>, Te<sub>48</sub>);

F7 (Bi<sub>19</sub>, Ge<sub>27</sub>, Te<sub>54</sub>).

3. (Currently Amended) An information-recording medium provided as an optical disk comprising a recording layer which is rewritable in accordance with phase-change caused by being irradiated with a laser beam, the information recording medium further comprising at least one other layer formed over the recording layer, wherein a relationship between a recording linear velocity V1 at a radius R1 and a recording linear velocity V2 at a position R2 disposed outside R1 satisfies  $V2/V1 \geq R2/R1$ , and the recording layer ~~contains~~ consists of Bi, Ge, and Te, and composition ratios thereof are within a range surrounded by the following respective points on a triangular composition diagram having apexes corresponding to Bi, Ge, and Te, and the recording layer has a film thickness of not more than 15 nm:

F2 (Bi<sub>2.5</sub>, Ge<sub>47</sub>, Te<sub>50.5</sub>);

C2 (Bi<sub>3</sub>, Ge<sub>47</sub>, Te<sub>50</sub>);

D2 (Bi<sub>4</sub>, Ge<sub>47</sub>, Te<sub>49</sub>);

D6 (Bi<sub>16</sub>, Ge<sub>37</sub>, Te<sub>47</sub>);

C8 (Bi<sub>30</sub>, Ge<sub>22</sub>, Te<sub>48</sub>);

F7 (Bi<sub>19</sub>, Ge<sub>27</sub>, Te<sub>54</sub>).

4. (Original) The information-recording medium according to claim 3, wherein  $R2/R1 \geq 1.5$  is satisfied.

5. (Original) The information-recording medium according to claim 3, wherein  $R2/R1 \geq 2.4$  is satisfied.

6. (Original) The information-recording medium according to claim 3, wherein  $8.14 \text{ m/s} \leq V1 \leq 8.61 \text{ m/s}$  is satisfied.

7. (Currently Amended) An information-recording medium comprising a recording layer which is rewritable multiple times and which is formed on a substrate having a recording track formed thereon, for recording information by causing phase-change in the recording layer under a recording condition in which a track pitch TP is not more than  $0.618 \mu\text{m}$ , the information recording medium further comprising at least one other layer formed over the recording layer, wherein the recording layer ~~contains~~ consists of Bi, Ge, and Te, and composition ratios thereof are within a range surrounded by the following respective points on a triangular composition diagram having apexes corresponding to Bi, Ge, and Te, and the recording layer has a film thickness of not more than 15 nm:

F2 ( $\text{Bi}_{2.5}, \text{Ge}_{47}, \text{Te}_{50.5}$ );

C2 ( $\text{Bi}_3, \text{Ge}_{47}, \text{Te}_{50}$ );

D2 ( $\text{Bi}_4, \text{Ge}_{47}, \text{Te}_{49}$ );

D6 ( $\text{Bi}_{16}, \text{Ge}_{37}, \text{Te}_{47}$ );

C8 ( $\text{Bi}_{30}, \text{Ge}_{22}, \text{Te}_{48}$ );

F7 ( $\text{Bi}_{19}, \text{Ge}_{27}, \text{Te}_{54}$ ).

8. (Currently Amended) An information-recording medium comprising a substrate and a recording layer which is rewritable in accordance with phase-change caused by being irradiated with a laser beam, the information recording medium further comprising at least one other layer formed over the recording layer, wherein the information-recording medium has a disk-shaped configuration, a groove is previously formed in a concentric form or in a spiral form on the substrate, at least one of the groove and a land between the grooves

is used as a recording track, at least one of the groove and the land is wobbled, and the recording layer ~~contains~~ consists of Bi, Ge, and Te, and composition ratios thereof are within a range surrounded by the following respective points on a triangular composition diagram having apexes corresponding to Bi, Ge, and Te, and the recording layer has a film thickness of not more than 15 nm:

F2 (Bi<sub>2.5</sub>, Ge<sub>47</sub>, Te<sub>50.5</sub>);

C2 (Bi<sub>3</sub>, Ge<sub>47</sub>, Te<sub>50</sub>);

D2 (Bi<sub>4</sub>, Ge<sub>47</sub>, Te<sub>49</sub>);

D6 (Bi<sub>16</sub>, Ge<sub>37</sub>, Te<sub>47</sub>);

C8 (Bi<sub>30</sub>, Ge<sub>22</sub>, Te<sub>48</sub>);

F7 (Bi<sub>19</sub>, Ge<sub>27</sub>, Te<sub>54</sub>).

9. (Canceled)